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Date:	December 1, 2003
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	Tel: 408/982-8200 ext. 1
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Pages	4 (excluding cover sheet)

First Inventor:	Mohamed N. Darwish
Title:	Trench MOSFET Having Implanted Drain-Drift Region And Process For Manufacturing The Same
Serial No.:	10/650,513
Examiner:	Unknown

Enclosed for filing in the above-identified application are the following:

Transmittal Form (1 page);

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Replacement Application Data Sheet (2 pages).

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		Application Number	ton of information unless it displays a valid OMB control num. 10/650,513		
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FORM		First Named Inventor	Mohamed N. Darwish		
		Group Art Unit	2812		
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CONFIRMATION NO. 5781

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FILING RECEIPT II 49 1010 200 X20 251 1044 1041 1041 1041 1045 2030 00; \$20 00 1045 400 1046 1046 OC000000011306279*

Date Mailed: 11/19/2003

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Filing Receipt Corrections, facsimile number 703-746-9195. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Mohamed N. Darwish, Campbell, CA;

- Santa Clara Assignment For Published Patent Application

Siliconix Incorporated, Gempbell, CA:

Domestic Priority data as claimed by applicant

This application is a DIV of 10/317,568 12/12/2002 which is a CIP of 09/898,652 07/03/2001 PAT 6,569,738

Foreign Applications

If Required, Foreign Filing License Granted: 11/19/2003

Projected Publication Date: 02/26/2004

Non-Publication Request: No

Early Publication Request: No

Title

Trench MOSFET having implanted drain-drift region and process for manufacturing the same